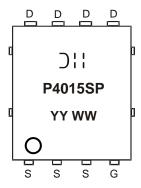


Marking Information



☐☐ = Manufacturer's Marking P4015SP = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 21 = 2021) WW = Week (01 to 53)

Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V _{GSS}	±25	V
Continuous Drain Current (Note 5) V _{GS} = -10V	Steady State	$T_A = +25$ °C $T_A = +70$ °C	lD	-8.5 -6.8	А
	t < 10s	T _A = +25°C T _A = +70°C	lD	-13.0 -10.5	А
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	lD	-11.0 -8.7	А
	t < 10s	$T_A = +25$ °C $T_A = +70$ °C	lo	-17.0 -13.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	Ірм	-100	Α		
Maximum Body Diode Continuous Current (Note 6)			Is	-11	Α
Avalanche Current (Note 8)			las	-22	Α
Avalanche Energy (Note 8)			Eas	242	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Dawar Dissipation (Note 5)	T _A = +25°C	6	1.3	W
Total Power Dissipation (Note 5)	T _A = +70°C	P_{D}	0.8	
Thermal Desistance Junction to Ambient (Note 5)	Steady State	D	96.4	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t < 10s	Reja	40.6	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	6	2.1	W
Total Fower Dissipation (Note o)	$T_A = +70^{\circ}C$	PD	1.4	
Thermal Desistance Investigate Archieut (Nete C)	Steady State	D	55.0	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t < 10s	Rөja	24.0	°C/W
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	4.15	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.

- Before mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
 Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).
 UIS in production with L = 0.1mH, T_J = +25°C.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

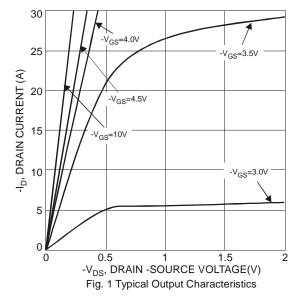
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BVDSS	-40	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μΑ	$V_{DS} = -40V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	Vgs(th)	-1.5	-2	-2.5	٧	$V_{DS} = V_{GS}$, $I_D = -250\mu A$
Statio Drain Source On Registence	Dagger	_	7	11	mΩ	$V_{GS} = -10V, I_{D} = -9.8A$
Static Drain-Source On-Resistance	RDS(ON)		9	15		V _G S = -4.5V, I _D = -9.8A
Forward Transfer Admittance	Y _{fs}		26	_	S	$V_{DS} = -20V, I_{D} = -9.8A$
Diode Forward Voltage	VsD	_	-0.7	-1	V	$V_{GS} = 0V$, $I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	Ciss	_	4,234	_		$V_{DS} = -20V$, $V_{GS} = 0V$ f = 1MHz
Output Capacitance	Coss	_	1,036	_	pF	
Reverse Transfer Capacitance	Crss	_	526	_		
Gate Resistance	Rg		7.77		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	_	47.5	_	V 00V V 5V	
Gate-Source Charge	Qgs	_	14.2	_	nC	$V_{DS} = -20V, V_{GS} = -5V$ $I_{D} = -9.8A$
Gate-Drain Charge	Qgd	_	13.5	_		
Turn-On Delay Time	t _{D(ON)}	_	13.2	_		$V_{GS} = -10V, V_{DD} = -20V, R_{G} = 6\Omega,$
Turn-On Rise Time	t _R	_	10	_		
Turn-Off Delay Time	tD(OFF)	_	302.7	_	ns	$I_D = -1A$, $R_L = 20\Omega$
Turn-Off Fall Time	tF	_	137.9	_		

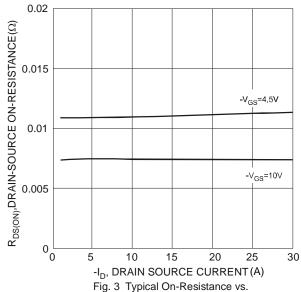
Notes:

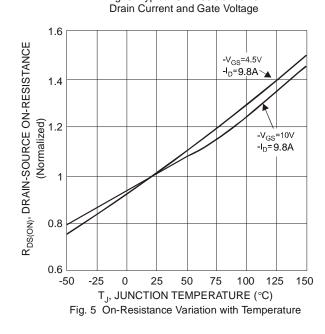
^{9.} Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to production testing.

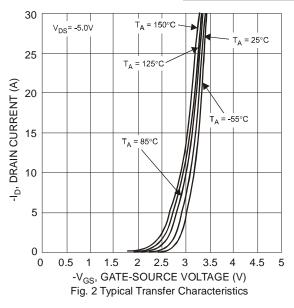


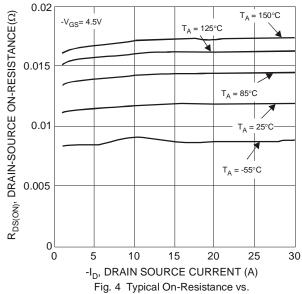












Drain Current and Temperature 0.02 $R_{DS(ON)}$, DRAIN-SOURCE ON-RESISTANCE (Ω) $V_{GS} = 4.5V$ 0.016 $-I_D = 9.8A$ 0.012 $-V_{GS} = 10V_{D}$ $-I_{D} = 9.8A$ 0.008 0.004 0 ∟ -50 100 125 25 50 75 T_{.I}, JUNCTION TEMPERATURE (°C)

Fig. 6 On-Resistance Variation with Temperature



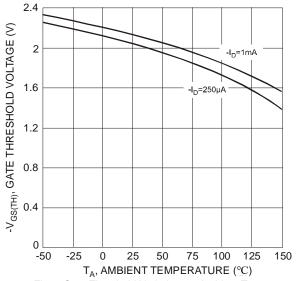
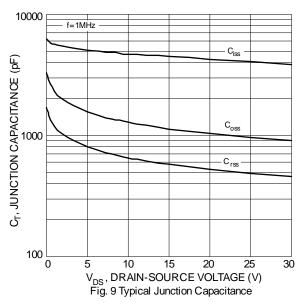
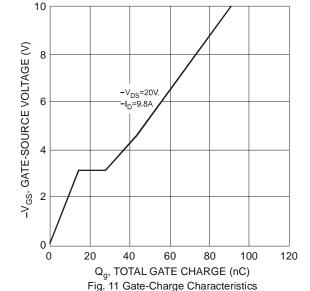
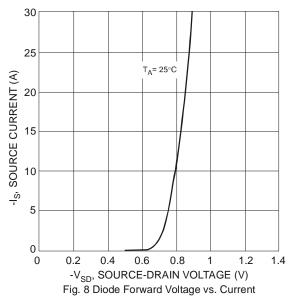


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







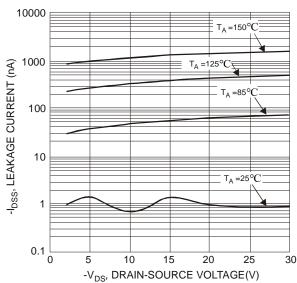


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage

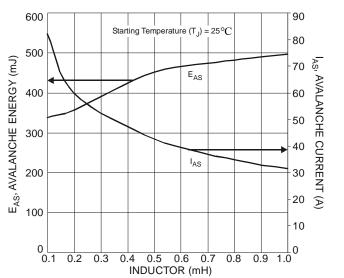
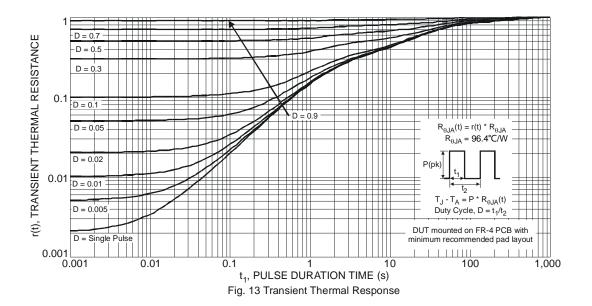


Fig. 12 Single-Pulse Avalanche Tested



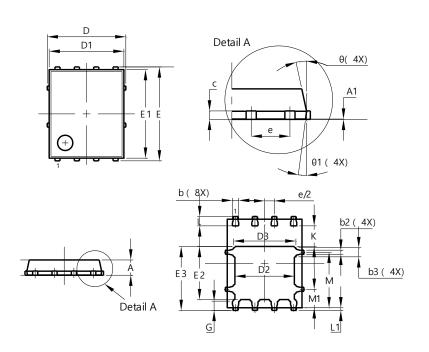




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

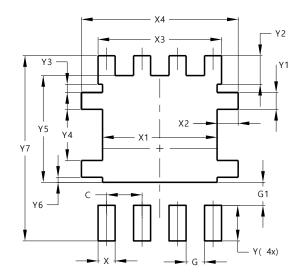


PowerDI5060-8						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
C	0.230	0.330	0.277			
D	5.15 BSC					
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
Е	6.15 BSC					
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е	1.27 BSC					
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Y	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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